

# Silicon Carbide (SiC) Schottky Diode - EliteSiC, 10 A, 650 V, D2, TO-220-2L

# FFSP1065B

Silicon Carbide (SiC) Schottky Diodes use a completely new technology that provides superior switching performance and higher reliability compared to Silicon. No reverse recovery current, temperature independent switching characteristics, and excellent thermal performance sets Silicon Carbide as the next generation of power semiconductor. System benefits include highest efficiency, faster operating frequency, increased power density, reduced EMI, and reduced system size and cost.

### **Features**

- Max Junction Temperature 175°C
- Avalanche Rated 49 mJ
- High Surge Current Capacity
- Positive Temperature Coefficient
- Ease of Paralleling
- No Reverse Recovery / No Forward Recovery
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

### **Applications**

- General Purpose
- SMPS, Solar Inverter, UPS
- Power Switching Circuit

### **ABSOLUTE MAXIMUM RATINGS**

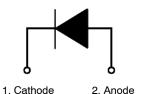
(T<sub>C</sub> = 25°C, Unless otherwise specified)

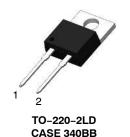
Symbol	Parame	Value	Unit	
$V_{RRM}$	Peak Repetitive Reverse	650	٧	
E <sub>AS</sub>	Single Pulse Avalanche I	49	mJ	
I <sub>F</sub>	Continuous Rectified For $T_C$ < 139°C	10	Α	
	Continuous Rectified For T <sub>C</sub> < 135°C	11		
I <sub>F, Max</sub>	Non-Repetitive Peak	T <sub>C</sub> = 25°C, 10 μs	650	Α
	Forward Surge Current	T <sub>C</sub> = 150°C, 10 μs	570	
I <sub>F, SM</sub>	Non-Repetitive Forward Surge Current	Half-Sine Pulse, t <sub>p</sub> = 8.3 ms	45	Α
P <sub>tot</sub>	Power Dissipation	T <sub>C</sub> = 25°C	75	W
		T <sub>C</sub> = 150°C	12.5	
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature Range		-55 to +175	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1.  $E_{AS}$  of 49 mJ is based on starting  $T_J = 25^{\circ}C$ , L = 0.5 mH,  $I_{AS} = 14$  A, V = 50 V.

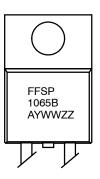
### **ELECTRICAL CONNECTION**





0.10201022

### MARKING DIAGRAM



FFSP1065B = Specific Device Code
A = Assembly Location
Y = Year
WW = Work Week
ZZ = Assembly Lot Code

### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

# FFSP1065B

# THERMAL CHARACTERISTICS

	Symbol	Parameter	Ratings	Unit
Γ	$R_{\theta JC}$	Thermal Resistance, Junction to Case, Max.	2.0	°C/W

# **ELECTRICAL CHARACTERISTICS** $T_C = 25^{\circ}C$ unless otherwise noted

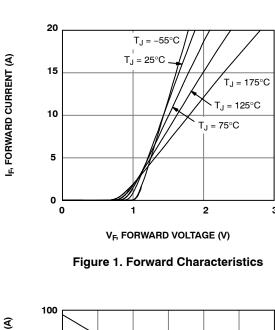
Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
V <sub>F</sub>	Forward Voltage	I <sub>F</sub> = 10 A, T <sub>C</sub> = 25°C	-	1.38	1.7	V
		I <sub>F</sub> = 10 A, T <sub>C</sub> = 125°C	-	1.6	2.0	
		I <sub>F</sub> = 10 A, T <sub>C</sub> = 175°C	-	1.72	2.4	
I <sub>R</sub>	Reverse Current	$V_R = 650 \text{ V}, T_C = 25^{\circ}\text{C}$	-	0.5	40	μΑ
		$V_R = 650 \text{ V}, T_C = 125^{\circ}\text{C}$	-	1.0	80	
		V <sub>R</sub> = 650 V, T <sub>C</sub> = 175°C	-	2.0	160	
$Q_{\mathbb{C}}$	Total Capacitive Charge	V = 400 V	-	25	-	nC
С	Total Capacitance	$V_{R} = 1 \text{ V, f} = 100 \text{ kHz}$	-	421	-	pF
		$V_R = 200 \text{ V, f} = 100 \text{ kHz}$	-	46	_	
		$V_R = 400 \text{ V}, f = 100 \text{ kHz}$	-	35	-	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

# PACKAGE MARKING AND ORDERING INFORMATION

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FFSP1065B	FFSP1065B	TO-220-2L	Tube	N/A	N/A	50 Units

# TYPICAL CHARACTERISTICS TJ = 25°C UNLESS OTHERWISE NOTED



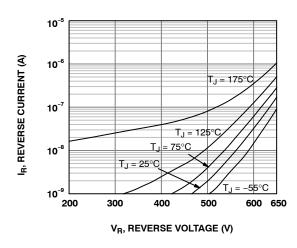
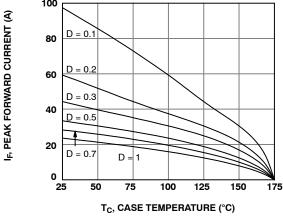


Figure 2. Reverse Characteristics



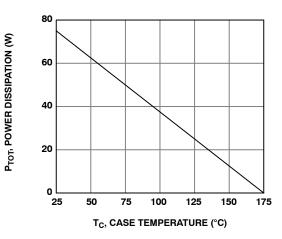
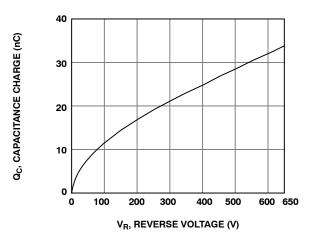


Figure 3. Current Derating

Figure 4. Power Dissipation



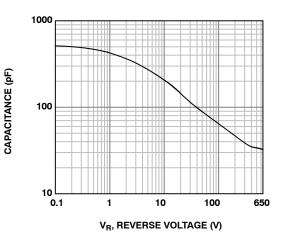


Figure 5. Capacitance Charge vs. Reverse Voltage

Figure 6. Capacitance vs. Reverse Voltage

# TYPICAL CHARACTERISTICS T<sub>J</sub> = 25°C UNLESS OTHERWISE NOTED (CONTINUED)

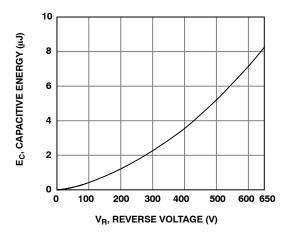


Figure 7. Capacitance Stored Energy

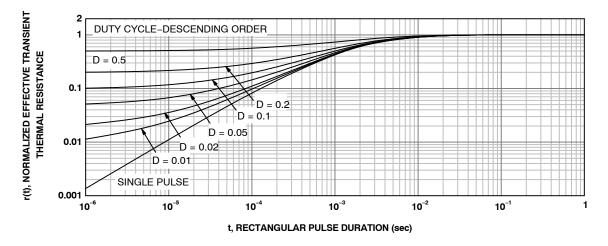


Figure 8. Junction-to-Case Transient Thermal Response Curve

# **TEST CIRCUIT AND WAVEFORMS**

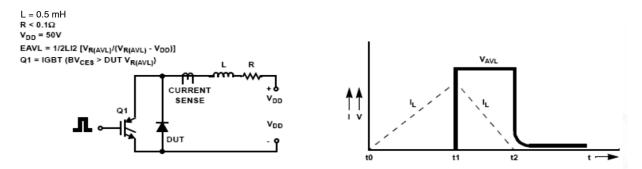
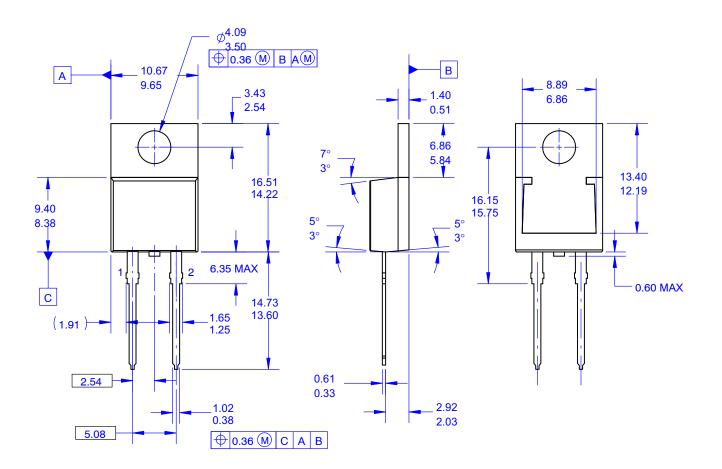


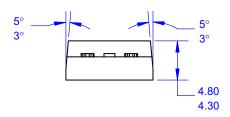
Figure 9. Unclamped Inductive Switching Test Circuit & Waveform



TO-220-2LD CASE 340BB ISSUE O

**DATE 31 AUG 2016** 





## **NOTES:**

- A. PACKAGE REFERENCE: JEDEC TO220,ISSUE K, VARIATION AC,DATED APRIL 2002.
- B. ALL DIMENSIONS ARE IN MILLIMETERS.
- C. DIMENSION AND TOLERANCE AS PER ASME Y14.5–2009.
- D. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH AND TIE BAR PROTRUSIONS.

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